

CHENMKO ENTERPRISE CO.,LTD

GLASS PASSIVATED JUNCTION TRANSIENT VOLTAGE SUPPRESSOR

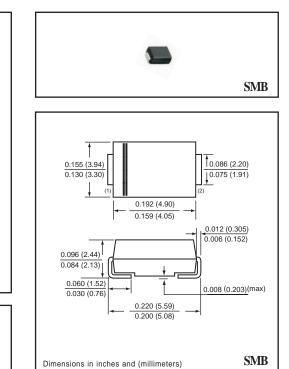
P6SBMJ7.5AGP-A

VOLTAGE- 7.5 VOLTS

600 WATTS PEAK POWER 5.0 WATTS STEADY STATE

GLAS GLAS GOC Halogens free devices 600 FEATURES

- * Plastic package
- * 600W surge capability at 1ms
- * Glass passivated chip junction in SMB Package
- * Excellent clamping capability
 * Low Zener Impedance
- Fast response time: typically less than 1.0ps from 0 volts to BV min.
- * Typical IR less than 1 uA above 10V
- * High temperature soldering guaranteed : 260°C/10 seconds at terminals



MECHANICAL DATA

Case: JEDEC SMB molded plastic Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end **Mounting Position:** Any

Weight: 0.003 ounce 0.093 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

DEVICES FOR BIDIRECTIONAL APPLICATIONS

For Bidirectional use C or CA Suffix for types P6SBMJ6.8A thru types P6SBMJ200A Electrical characteristics apply in both directions.

MAXIMUM RATINGES (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Peak Power Dissipation at TA = 25° C, Tp = 1ms (Note1)	Ррк	Minimum 600	Watts
Steady State Power Dissipation at TL = 75°C	Pd	5.0	Watts
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Note 2)	IFSM	100	Amps
Operating and Storage Temperature Range	TJ, TSTG	-65 to +175	°C

NOTES : 1. Non-repetitive current pulse, per Fig. 3 and derated above $T_A = 25^{\circ}C$ per Fig. 2.

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2. 8.3ms single half sine-wave, duty cycle = 4 pulses per minute maximum. 3. PC Board Mounted on 0.2 X 0.2" (5 X 5mm) copper pad area

